

LOW POWER DUAL VOLTAGE COMPARATORS

- WIDE SINGLE SUPPLY VOLTAGE RANGE OR DUAL SUPPLIES +2V TO +36V OR ±1V TO ±18V
- VERY LOW SUPPLY CURRENT (0.4mA) INDEPENDENT OF SUPPLY VOLTAGE (1mW/comparator at +5V)
- LOW INPUT BIAS CURRENT: 25nA TYP
- LOW INPUT OFFSET CURRENT: ±5nA TYP
- INPUT COMMON-MODE VOLTAGE RANGE INCLUDES GROUND
- LOW OUTPUT SATURATION VOLTAGE: 250mV TYP. (I_O = 4mA)
- DIFFERENTIAL INPUT VOLTAGE RANGE EQUAL TO THE SUPPLY VOLTAGE
- TTL, DTL, ECL, MOS, CMOS COMPATIBLE OUTPUTS

DESCRIPTION

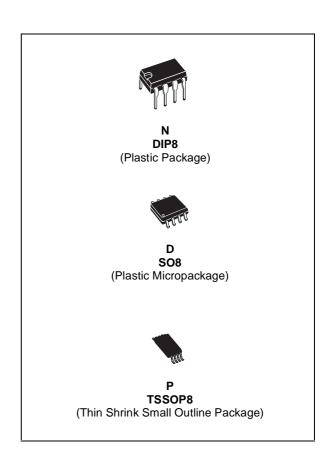
This device consists of two independent low power voltage comparators designed specifically to operate from a single supply over a wide range of voltages. Operation from split power supplies is also possible.

These comparators also have a unique characteristic in that the input common-mode voltage range includes ground even though operated from a single power supply voltage.

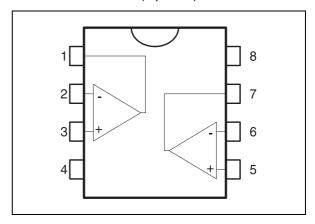
ORDER CODE

Part	Temperature	Package			
Number	Range	N D		Р	
LM2903	-40°C, +125°C	•	•	•	

- N = Dual in Line Package (DIP)
- **D** = Small Outline Package (SO) also available in Tape & Reel (DT)
- P = Thin Shrink Small Outline Package (TSSOP) only available in Tape & Reel (PT)

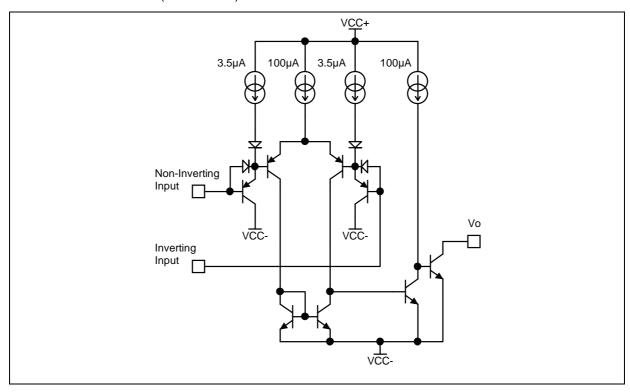


PIN CONNECTIONS (top view)



June 2003 1/9

SCHEMATIC DIAGRAM (1/2 LM2903)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	±18 to 36	V
V _{ID}	Differential Input Voltage	±36	V
V _I	Input Voltage	-0.3 to +36	V
	Output Short-circuit to Ground 1)	Infinite	
P _d	Power Dissipation ²⁾ DIP8 SO8 TSSOP8	1250 710 625	mW
T _{Junction}	Junction Temperature	+150	°C
T _{stg}	Storage Temperature Range	-65 to +150	°C

Short-circuit from the output to V_{cc}⁺ can cause excessive heating and eventual destruction. The maximum output current is approximately 20mA, independent of the magnitude of V_{cc}⁺

OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V _{icm}	Common Mode Input Voltage Range	0 to V _{CC} ⁺ -1.5	V
T _{oper}	Operating Free-Air Temperature range	-40 to +125	°C

2/9

^{2.} Pd is calculated with T_{amb} = +25°C, T_j = +150°C and R_{thja} = 100°C/W for DIP8 package = 175°C/W for SO8 package = 200°C/W for TSSOP8 package

ELECTRICAL CHARACTERISTICS

 V_{CC}^+ = 5V, V_{cc}^- = GND, T_{amb} = 25°C (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{IO}	Input Offset Voltage ¹⁾ $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}.$		1	7 15	mV
I _{IO}	Input Offset Current $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}.$		5	50 150	nA
I _{IB}	Input Bias Current $^{2)}$ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$.		25	250 400	nA
A _{VD}	Large Signal Voltage Gain ($V_{cc} = 15V, R_L = 15k\Omega, V_0 = 1 \text{ to } 11V$)	25	200		V/mV
I _{CC}	Supply Current (all comparators) $V_{CC} = 5V, \text{ no load}$ $V_{CC} = 30V, \text{ no load}$		0.4 1	1 2.5	mA
$V_{\rm ICM}$	Input Common Mode Voltage Range $(V_{cc}=30V)^{3}$ $T_{amb}=+25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$.	0 0		V _{CC} ⁺ -1.5 V _{CC} ⁺ -2	>
V _{ID}	Differential Input Voltage ⁴⁾			V _{CC} ⁺	V
V _{OL}	Low Level Output Voltage (V_{id} = -1V, I_{sink} = 4mA) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		250	400 700	mV
I _{OH}	High Level Output Current ($V_{CC} = V_o = 30V$, $V_{id} = 1V$) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		0.1	1	nΑ μΑ
I _{SINK}	Output Sink Current (V _{id} = -1V,V _o = 1.5V)	6	16		mA
t _{RE}	Small Signal Response Time $^{5)}$ (R _L = 5.1k Ω to V _{CC} ⁺)		1.3		μs
t _{REL}	Large Signal Response Time ⁶⁾ TTL Input (V _{ref} = +1.4 V, R _L =5.1kΩ to V _{CC} ⁺) Output Signal at 50% of final value Output Signal at 95 % of final value			500 1	ns µs

^{1.} At output switch point, $V_{O} \approx 1.4V$, $R_{S} = 0\Omega$ with V_{CC}^{+} from 5V to 30V, and over the full input common-mode range (0V to V_{CC}^{+} –1.5V).

^{2.} The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output, so no loading charge exists on the reference of input lines

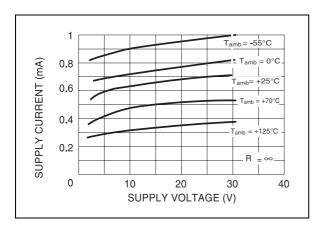
The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is V_{CC}⁺-1.5V, but either or both inputs can go to +30V without damage.

^{4.} Positive excursions of input voltage may exceed the power supply level. As long as the other voltage remains within the common-mode range, the comparator will provide a proper output state.
The low input voltage state must not be less than -0.3V (or 0.3V below the negative power supply, if used)

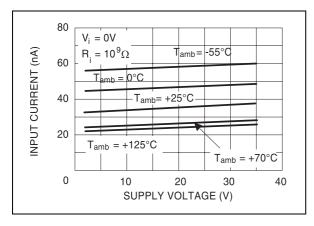
The response time specified is for a 100mV input step with 5mV overdrive.

^{6.} Maximum values are guaranteed by design & evaluation.

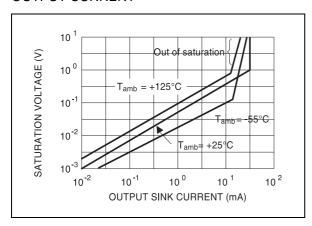
SUPPLY CURRENT versus SUPPLY VOLTAGE



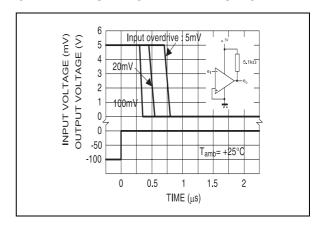
INPUT CURRENT versus SUPPLY VOLTAGE



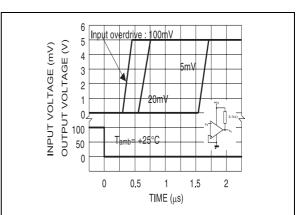
OUTPUT SATURATION VOLTAGE versus OUTPUT CURRENT



RESPONSE TIME FOR VARIOUS INPUT OVERDRIVES - NEGATIVE TRANSITION



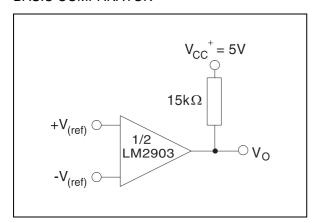
RESPONSE TIME FOR VARIOUS INPUT OVERDRIVES - POSITIVE TRANSITION



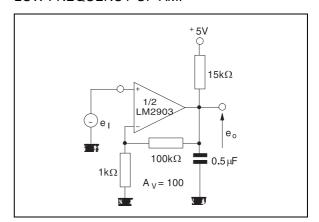
4/9

TYPICAL APPLICATIONS

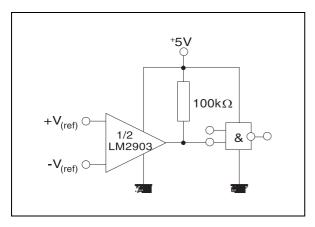
BASIC COMPARATOR



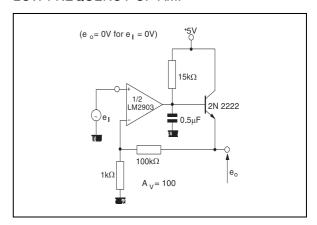
LOW FREQUENCY OP AMP



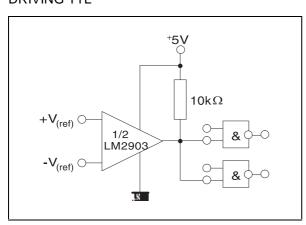
DRIVING CMOS



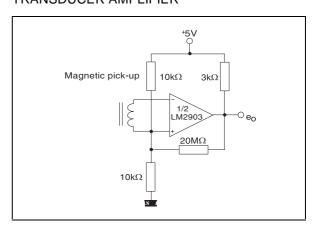
LOW FREQUENCY OP AMP



DRIVING TTL

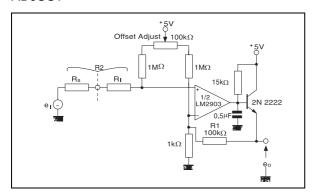


TRANSDUCER AMPLIFIER

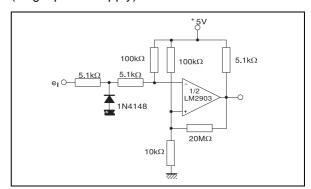


LM2903

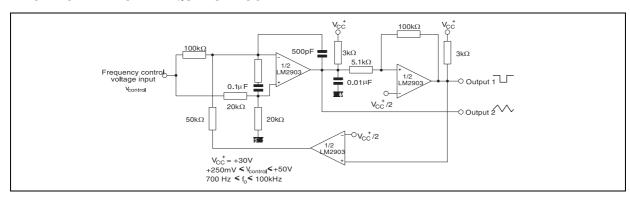
LOW FREQUENCY OP AMP WITH OFFSET **ADJUST**



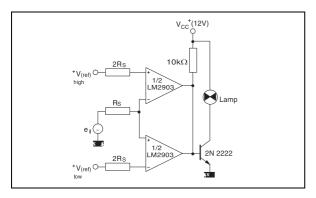
ZERO CROSSING DETECTOR (single power supply)



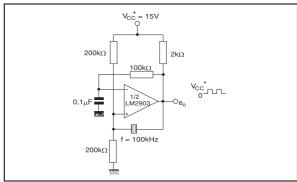
TWO-DECADE HIGH-FREQUENCY VCO



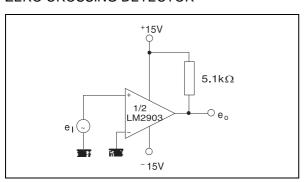
LIMIT COMPARATOR



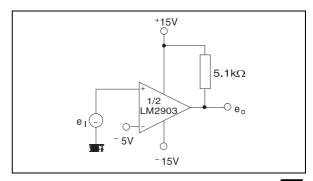
CRYSTAL CONTROLLED OSCILLATOR



SPLIT-SUPPLY APPLICATIONS ZERO CROSSING DETECTOR



COMPARATOR WITH A NEGATIVE REFERENCE

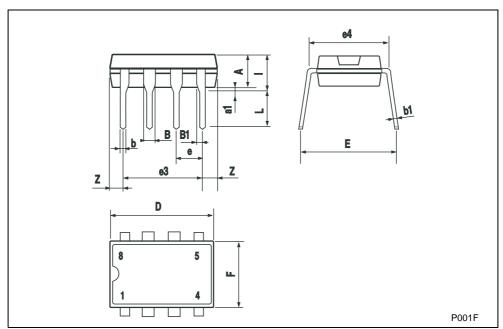


47/ 6/9

PACKAGE MECHANICAL DATA

Plastic DIP-8 MECHANICAL DATA

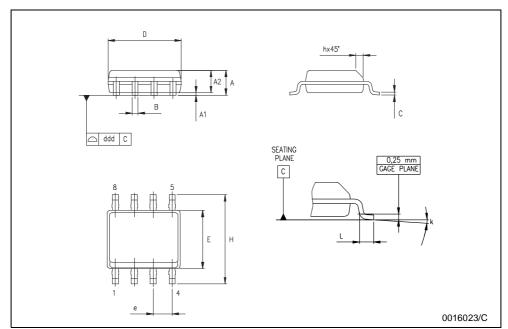
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α		3.3			0.130	
a1	0.7			0.028		
В	1.39		1.65	0.055		0.065
B1	0.91		1.04	0.036		0.041
b		0.5			0.020	
b1	0.38		0.5	0.015		0.020
D			9.8			0.386
Е		8.8			0.346	
е		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			7.1			0.280
I			4.8			0.189
L		3.3			0.130	
Z	0.44		1.6	0.017		0.063



PACKAGE MECHANICAL DATA

SO-8 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.04		0.010
A2	1.10		1.65	0.043		0.065
В	0.33		0.51	0.013		0.020
С	0.19		0.25	0.007		0.010
D	4.80		5.00	0.189		0.197
E	3.80		4.00	0.150		0.157
е		1.27			0.050	
Н	5.80		6.20	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	8° (max.)					
ddd			0.1			0.04

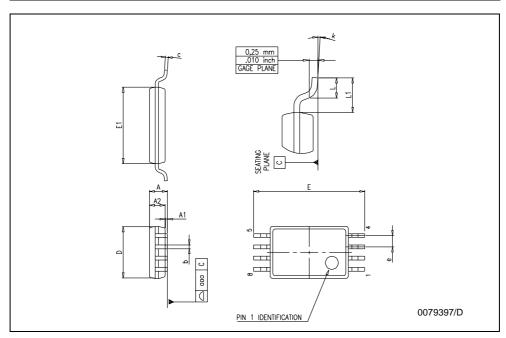


8/9

PACKAGE MECHANICAL DATA

TSSOP8 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А			1.2			0.047
A1	0.05		0.15	0.002		0.006
A2	0.80	1.00	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
С	0.09		0.20	0.004		0.008
D	2.90	3.00	3.10	0.114	0.118	0.122
Е	6.20	6.40	6.60	0.244	0.252	0.260
E1	4.30	4.40	4.50	0.169	0.173	0.177
е		0.65			0.0256	
К	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030
L1		1			0.039	



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